## He Cheng

## List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/918029/publications.pdf

Version: 2024-02-01

2682572 2917675 3 34 2 2 citations h-index g-index papers 3 3 3 30 docs citations times ranked citing authors all docs

#	Article	IF	CITATIONS
1	A Charge Density Model of Silicon-nanowire GAA MOSFET Incoroperating the Source-drian Tunneling Effect for IC Design. , 2021, , .		2
2	Nanowire gate-all-around MOSFETs modeling: ballistic transport incorporating the source-to-drain tunneling. Japanese Journal of Applied Physics, 2020, 59, 074002.	1.5	9
3	Analytic compact model of ballistic and quasi-ballistic transport for cylindrical gate-all-around MOSFET including drain-induced barrier lowering effect. Journal of Computational Electronics, 2015, 14, 321-328.	2.5	23